

# MC79L00A Series

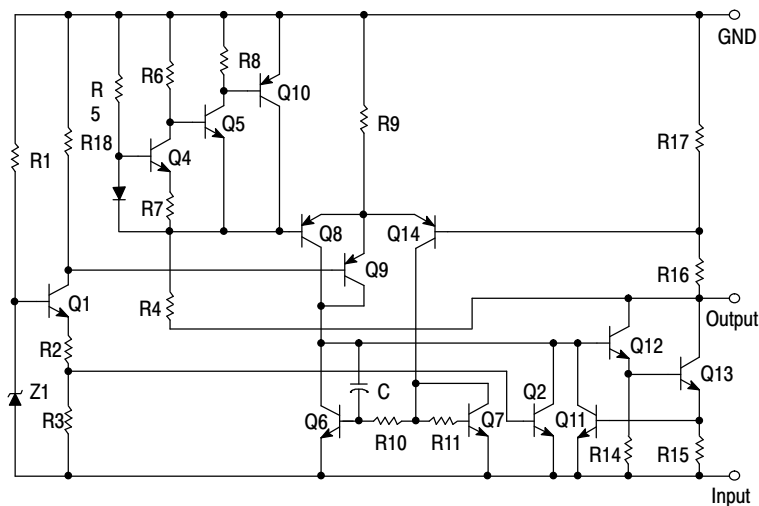
## 100 mA Negative Voltage Regulators

The MC79L00A Series negative voltage regulators are inexpensive, easy-to-use devices suitable for numerous applications requiring up to 100 mA. Like the higher powered MC7900 Series negative regulators, this series features thermal shutdown and current limiting, making them remarkably rugged. In most applications, no external components are required for operation.

The MC79L00A devices are useful for on-card regulation or any other application where a regulated negative voltage at a modest current level is needed. These regulators offer substantial advantage over the common resistor/Zener diode approach.

### Features

- No External Components Required
- Internal Short Circuit Current Limiting
- Internal Thermal Overload Protection
- Low Cost
- Complementary Positive Regulators Offered (MC78L00 Series)
- Pb-Free Packages are Available



\* Automotive temperature range selections are available with special test conditions and additional tests in 5, 12 and 15 V devices. Contact your local ON Semiconductor sales office for information.

**Figure 1. Representative Schematic Diagram**

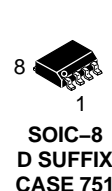


**ON Semiconductor®**

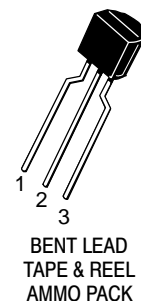
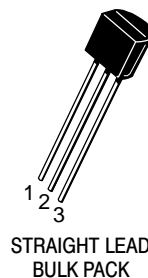
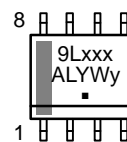
[www.onsemi.com](http://www.onsemi.com)

### THREE-TERMINAL LOW CURRENT NEGATIVE FIXED VOLTAGE REGULATORS

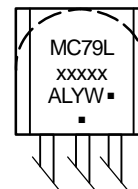
#### MARKING DIAGRAMS



Pin 1.  $V_{out}$   
2.  $V_{in}$   
3.  $V_{in}$   
4. NC  
5. GND  
6.  $V_{in}$   
7.  $V_{in}$   
8. NC



Pin 1. Ground  
2. Input  
3. Output



xxx = Specific Device Code  
A = Assembly Location  
L = Wafer Lot  
Y = Year  
W = Work Week  
y = B or C  
■ = Pb-Free Package

(Note: Microdot may be in either location)

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.

## MC79L00A Series

### MAXIMUM RATINGS (T<sub>A</sub> = +25°C, unless otherwise noted.)

Rating	Symbol	Value	Unit
Input Voltage (-5 V) (-12, -15, -18 V) (-24 V)	V <sub>I</sub>	-30 -35 -40	Vdc
Power Dissipation Case 29 (TO-92 Type) T <sub>A</sub> = 25°C Thermal Resistance, Junction-to-Ambient Thermal Resistance, Junction-to-Case  Case 751 (SOIC-8 Type) (Note 1) T <sub>A</sub> = 25°C Thermal Resistance, Junction-to-Ambient Thermal Resistance, Junction-to-Case	PD R <sub>θJA</sub> R <sub>θJC</sub>  PD R <sub>θJA</sub> R <sub>θJC</sub>	Internally Limited 160 83  Internally Limited 180 45	W °C/W °C/W  W °C/W °C/W
Storage Temperature Range	T <sub>stg</sub>	-65 to +150	°C
Junction Temperature	T <sub>J</sub>	+150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. SOIC-8 Junction-to-Ambient Thermal Resistance is for minimum recommended pad size. Refer to Figure 9 for Thermal Resistance variation versus pad size.

\*This device series contains ESD protection and exceeds the following tests:

Human Body Model 2000 V per MIL\_STD\_883, Method 3015

Machine Model Method 200 V.

### ELECTRICAL CHARACTERISTICS (V<sub>I</sub> = -10 V, I<sub>O</sub> = 40 mA, C<sub>I</sub> = 0.33 μF, C<sub>O</sub> = 0.1 μF, -40°C < T<sub>J</sub> < +125°C (for MC79LXXAB), 0°C < T<sub>J</sub> < +125°C (for MC79LXXAC)).

Characteristics	Symbol	MC79L05AC, AB			Unit
		Min	Typ	Max	
Output Voltage (T <sub>J</sub> = +25°C)	V <sub>O</sub>	-4.8	-5.0	-5.2	Vdc
Input Regulation (T <sub>J</sub> = +25°C) -7.0 Vdc ≥ V <sub>I</sub> ≥ -20 Vdc -8.0 Vdc ≥ V <sub>I</sub> ≥ -20 Vdc	Reg <sub>line</sub>	- -	- -	150 100	mV
Load Regulation T <sub>J</sub> = +25°C, 1.0 mA ≤ I <sub>O</sub> ≤ 100 mA 1.0 mA ≤ I <sub>O</sub> ≤ 40 mA	Reg <sub>load</sub>	- -	- -	60 30	mV
Output Voltage -7.0 Vdc ≥ V <sub>I</sub> ≥ -20 Vdc, 1.0 mA ≤ I <sub>O</sub> ≤ 40 mA V <sub>I</sub> = -10 Vdc, 1.0 mA ≤ I <sub>O</sub> ≤ 70 mA	V <sub>O</sub>	-4.75 -4.75	- -	-5.25 -5.25	Vdc
Input Bias Current (T <sub>J</sub> = +25°C) (T <sub>J</sub> = +125°C)	I <sub>IB</sub>	- -	- -	6.0 5.5	mA
Input Bias Current Change -8.0 Vdc ≥ V <sub>I</sub> ≥ -20 Vdc 1.0 mA ≤ I <sub>O</sub> ≤ 40 mA	I <sub>IB</sub>	- -	- -	1.5 0.1	mA
Output Noise Voltage (T <sub>A</sub> = +25°C, 10 Hz ≤ f ≤ 100 kHz)	V <sub>n</sub>	-	40	-	μV
Ripple Rejection (-8.0 ≥ V <sub>I</sub> ≥ -18 Vdc, f = 120 Hz, T <sub>J</sub> = +25°C)	RR	41	49	-	dB
Dropout Voltage (I <sub>O</sub> = 40 mA, T <sub>J</sub> = +25°C)	V <sub>I</sub> - V <sub>O</sub>	-	1.7	-	Vdc

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

## MC79L00A Series

**ELECTRICAL CHARACTERISTICS** ( $V_I = -19\text{ V}$ ,  $I_O = 40\text{ mA}$ ,  $C_I = 0.33\text{ }\mu\text{F}$ ,  $C_O = 0.1\text{ }\mu\text{F}$ ,  $-40^\circ\text{C} < T_J + 125^\circ\text{C}$  (for MC79LXXAB),  $0^\circ\text{C} < T_J < +125^\circ\text{C}$  (for MC79LXXAC)).

Characteristics	Symbol	MC79L12AC, AB			Unit
		Min	Typ	Max	
Output Voltage ( $T_J = +25^\circ\text{C}$ )	$V_O$	-11.5	-12	-12.5	Vdc
Input Regulation ( $T_J = +25^\circ\text{C}$ ) -14.5 Vdc $\geq V_I \geq -27\text{ Vdc}$ -16 Vdc $\geq V_I \geq -27\text{ Vdc}$	$\text{Reg}_{\text{line}}$	- -	- -	250 200	mV
Load Regulation $T_J = +25^\circ\text{C}$ , $1.0\text{ mA} \leq I_O \leq 100\text{ mA}$ $1.0\text{ mA} \leq I_O \leq 40\text{ mA}$	$\text{Reg}_{\text{load}}$	- -	- -	100 50	mV
Output Voltage -14.5 Vdc $\geq V_I \geq -27\text{ Vdc}$ , $1.0\text{ mA} \leq I_O \leq 40\text{ mA}$ $V_I = -19\text{ Vdc}$ , $1.0\text{ mA} \leq I_O \leq 70\text{ mA}$	$V_O$	-11.4 -11.4	- -	-12.6 -12.6	Vdc
Input Bias Current ( $T_J = +25^\circ\text{C}$ ) ( $T_J = +125^\circ\text{C}$ )	$I_{IB}$	- -	- -	6.5 6.0	mA
Input Bias Current Change -16 Vdc $\geq V_I \geq -27\text{ Vdc}$ $1.0\text{ mA} \leq I_O \leq 40\text{ mA}$	$I_{IB}$	- -	- -	1.5 0.2	mA
Output Noise Voltage ( $T_A = +25^\circ\text{C}$ , $10\text{ Hz} \leq f \leq 100\text{ kHz}$ )	$V_n$	-	80	-	$\mu\text{V}$
Ripple Rejection ( $-15 \leq V_I \leq -25\text{ Vdc}$ , $f = 120\text{ Hz}$ , $T_J = +25^\circ\text{C}$ )	RR	37	42	-	dB
Dropout Voltage ( $I_O = 40\text{ mA}$ , $T_J = +25^\circ\text{C}$ )	$ V_I - V_O $	-	1.7	-	Vdc

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

**ELECTRICAL CHARACTERISTICS** ( $V_I = -23\text{ V}$ ,  $I_O = 40\text{ mA}$ ,  $C_I = 0.33\text{ }\mu\text{F}$ ,  $C_O = 0.1\text{ }\mu\text{F}$ ,  $-40^\circ\text{C} < T_J + 125^\circ\text{C}$  (for MC79LXXAB),  $0^\circ\text{C} < T_J < +125^\circ\text{C}$  (for MC79LXXAC)).

Characteristics	Symbol	MC79L15AC, AB			Unit
		Min	Typ	Max	
Output Voltage ( $T_J = +25^\circ\text{C}$ )	$V_O$	-14.4	-15	-15.6	Vdc
Input Regulation ( $T_J = +25^\circ\text{C}$ ) -17.5 Vdc $\geq V_I \geq -30\text{ Vdc}$ -20 Vdc $\geq V_I \geq -30\text{ Vdc}$	$\text{Reg}_{\text{line}}$	- -	- -	300 250	mV
Load Regulation $T_J = +25^\circ\text{C}$ , $1.0\text{ mA} \leq I_O \leq 100\text{ mA}$ $1.0\text{ mA} \leq I_O \leq 40\text{ mA}$	$\text{Reg}_{\text{load}}$	- -	- -	150 75	mV
Output Voltage -17.5 Vdc $\geq V_I \geq -V_{dc}$ , $1.0\text{ mA} \leq I_O \leq 40\text{ mA}$ $V_I = -23\text{ Vdc}$ , $1.0\text{ mA} \leq I_O \leq 70\text{ mA}$	$V_O$	-14.25 -14.25	- -	-15.75 -15.75	Vdc
Input Bias Current ( $T_J = +25^\circ\text{C}$ ) ( $T_J = +125^\circ\text{C}$ )	$I_{IB}$	- -	- -	6.5 6.0	mA
Input Bias Current Change -20 Vdc $\geq V_I \geq -30\text{ Vdc}$ $1.0\text{ mA} \leq I_O \leq 40\text{ mA}$	$\Delta I_{IB}$	- -	- -	1.5 0.1	mA
Output Noise Voltage ( $T_A = +25^\circ\text{C}$ , $10\text{ Hz} \leq f \leq 100\text{ kHz}$ )	$V_n$	-	90	-	$\mu\text{V}$
Ripple Rejection ( $-18.5 \leq V_I \leq -28.5\text{ Vdc}$ , $f = 120\text{ Hz}$ )	RR	34	39	-	dB
Dropout Voltage $I_O = 40\text{ mA}$ , $T_J = +25^\circ\text{C}$	$ V_I - V_O $	-	1.7	-	Vdc

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

## MC79L00A Series

**ELECTRICAL CHARACTERISTICS** ( $V_I = -27\text{ V}$ ,  $I_O = 40\text{ mA}$ ,  $C_I = 0.33\text{ }\mu\text{F}$ ,  $C_O = 0.1\text{ }\mu\text{F}$ ,  $-40^\circ\text{C} < T_J + 125^\circ\text{C}$  (for MC79LXXAB),  $0^\circ\text{C} < T_J < +125^\circ\text{C}$  (for MC79LXXAC), unless otherwise noted).

Characteristics	Symbol	MC79L18AC			Unit
		Min	Typ	Max	
Output Voltage ( $T_J = +25^\circ\text{C}$ )	$V_O$	-17.3	-18	-18.7	Vdc
Input Regulation ( $T_J = +25^\circ\text{C}$ ) -20.7 Vdc $\geq V_I \geq -33\text{ Vdc}$ -21.4 Vdc $\geq V_I \geq -33\text{ Vdc}$ -22 Vdc $\geq V_I \geq -33\text{ Vdc}$ -21 Vdc $\geq V_I \geq -33\text{ Vdc}$	$\text{Reg}_{\text{line}}$	-	-	325 - - 275	mV
Load Regulation $T_J = +25^\circ\text{C}$ , $1.0\text{ mA} \leq I_O \leq 100\text{ mA}$ $1.0\text{ mA} \leq I_O \leq 40\text{ mA}$	$\text{Reg}_{\text{load}}$	- -	- -	170 85	mV
Output Voltage -20.7 Vdc $\geq V_I \geq -33\text{ Vdc}$ , $1.0\text{ mA} \leq I_O \leq 40\text{ mA}$ -21.4 Vdc $\geq V_I \geq -33\text{ Vdc}$ , $1.0\text{ mA} \leq I_O \leq 40\text{ mA}$ $V_I = -27\text{ Vdc}$ , $1.0\text{ mA} \leq I_O \leq 70\text{ mA}$	$V_O$	-17.1 - -17.1	- - -	-18.9 - -18.9	Vdc
Input Bias Current ( $T_J = +25^\circ\text{C}$ ) ( $T_J = +125^\circ\text{C}$ )	$I_{IB}$	- -	- -	6.5 6.0	mA
Input Bias Current Change -21 Vdc $\geq V_I \geq -33\text{ Vdc}$ -27 Vdc $\geq V_I \geq -33\text{ Vdc}$ $1.0\text{ mA} \leq I_O \leq 40\text{ mA}$	$I_{IB}$	- - -	- - -	1.5 - 0.1	mA
Output Noise Voltage ( $T_A = +25^\circ\text{C}$ , $10\text{ Hz} \leq f \leq 100\text{ kHz}$ )	$V_n$	-	150	-	$\mu\text{V}$
Ripple Rejection ( $-23 \leq V_I \leq -33\text{ Vdc}$ , $f = 120\text{ Hz}$ , $T_J = +25^\circ\text{C}$ )	RR	33	48	-	dB
Dropout Voltage $I_O = 40\text{ mA}$ , $T_J = +25^\circ\text{C}$	$ V_I - V_O $	-	1.7	-	Vdc

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

**ELECTRICAL CHARACTERISTICS** ( $V_I = -33\text{ V}$ ,  $I_O = 40\text{ mA}$ ,  $C_I = 0.33\text{ }\mu\text{F}$ ,  $C_O = 0.1\text{ }\mu\text{F}$ ,  $-40^\circ\text{C} < T_J + 125^\circ\text{C}$  (for MC79LXXAB),  $0^\circ\text{C} < T_J < +125^\circ\text{C}$  (for MC79LXXAC), unless otherwise noted).

Characteristics	Symbol	MC79L24AC			Unit
		Min	Typ	Max	
Output Voltage ( $T_J = +25^\circ\text{C}$ )	$V_O$	-23	-24	-25	Vdc
Input Regulation ( $T_J = +25^\circ\text{C}$ ) -27 Vdc $\geq V_I \geq -38\text{ Vdc}$ -27.5 Vdc $\geq V_I \geq -38\text{ Vdc}$ -28 Vdc $\geq V_I \geq -38\text{ Vdc}$	$\text{Reg}_{\text{line}}$	- - -	- - -	350 - 300	mV
Load Regulation $T_J = +25^\circ\text{C}$ , $1.0\text{ mA} \leq I_O \leq 100\text{ mA}$ $1.0\text{ mA} \leq I_O \leq 40\text{ mA}$	$\text{Reg}_{\text{load}}$	- -	- -	200 100	mV
Output Voltage -27 Vdc $\geq V_I \geq -38\text{ Vdc}$ , $1.0\text{ mA} \leq I_O \leq 40\text{ mA}$ -28 Vdc $\geq V_I \geq -38\text{ Vdc}$ , $1.0\text{ mA} \leq I_O \leq 40\text{ mA}$ $V_I = -33\text{ Vdc}$ , $1.0\text{ mA} \leq I_O \leq 70\text{ mA}$	$V_O$	-22.8 - -22.8	- - -	-25.2 - -25.2	Vdc
Input Bias Current ( $T_J = +25^\circ\text{C}$ ) ( $T_J = +125^\circ\text{C}$ )	$I_{IB}$	- -	- -	6.5 6.0	mA
Input Bias Current Change -28 Vdc $\geq V_I \geq -38\text{ Vdc}$ $1.0\text{ mA} \leq I_O \leq 40\text{ mA}$	$\Delta I_{IB}$	- -	- -	1.5 0.1	mA
Output Noise Voltage ( $T_A = +25^\circ\text{C}$ , $10\text{ Hz} \leq f \leq 100\text{ kHz}$ )	$V_n$	-	200	-	$\mu\text{V}$
Ripple Rejection ( $-29 \leq V_I \leq -35\text{ Vdc}$ , $f = 120\text{ Hz}$ , $T_J = +25^\circ\text{C}$ )	RR	31	47	-	dB
Dropout Voltage $I_O = 40\text{ mA}$ , $T_J = +25^\circ\text{C}$	$ V_I - V_O $	-	1.7	-	Vdc

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

# MC79L00A Series

## APPLICATIONS INFORMATION

### Design Considerations

The MC79L00A Series of fixed voltage regulators are designed with Thermal Overload Protections that shuts down the circuit when subjected to an excessive power overload condition, Internal Short Circuit Protection that limits the maximum current the circuit will pass.

In many low current applications, compensation capacitors are not required. However, it is recommended that the regulator input be bypassed with a capacitor if the regulator is connected to the power supply filter with long wire length, or if the output load capacitance is large. An input bypass capacitor should be selected to provide good

high-frequency characteristics to insure stable operation under all load conditions. A  $0.33\ \mu\text{F}$  or larger tantalum, mylar, or other capacitor having low internal impedance at high frequencies should be chosen. The bypass capacitor should be mounted with the shortest possible leads directly across the regulator's input terminals. Normally good construction techniques should be used to minimize ground loops and lead resistance drops since the regulator has no external sense lead. Bypassing the output is also recommended.

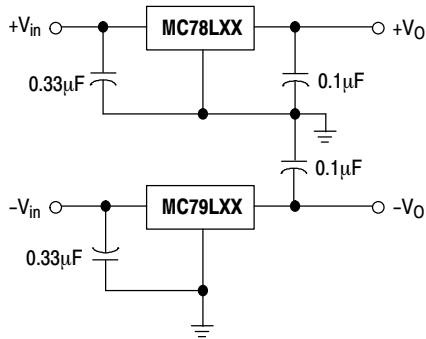
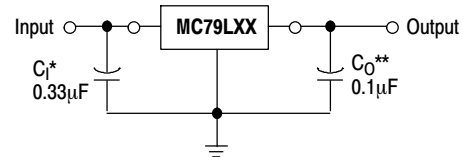


Figure 2. Positive and Negative Regulator



A common ground is required between the input and the output voltages. The input voltage must remain typically 2.0 V above the output voltage even during the low point on the ripple voltage.

\*  $C_1$  is required if regulator is located an appreciable distance from the power supply filter

\*\*  $C_0$  improves stability and transient response.

Figure 3. Standard Application

# MC79L00A Series

## TYPICAL CHARACTERISTICS

( $T_A = +25^\circ\text{C}$ , unless otherwise noted.)

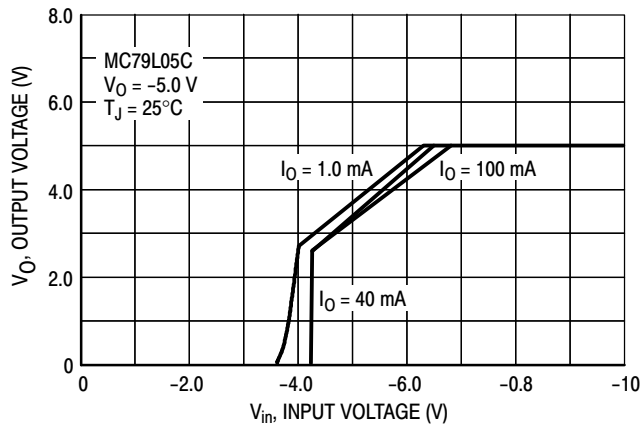


Figure 4. Dropout Characteristics

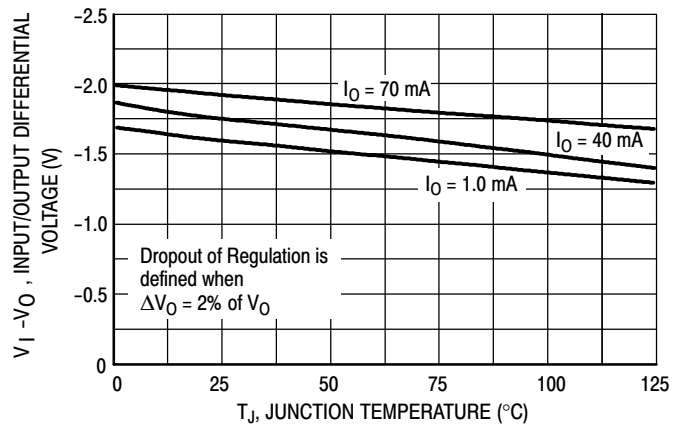


Figure 5. Dropout Voltage versus Junction Temperature

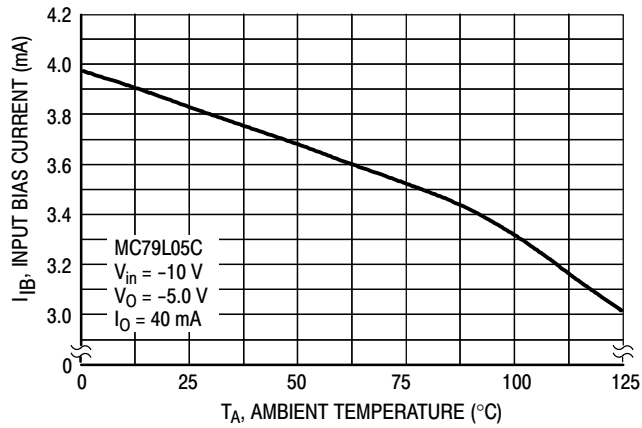


Figure 6. Input Bias Current versus Ambient Temperature

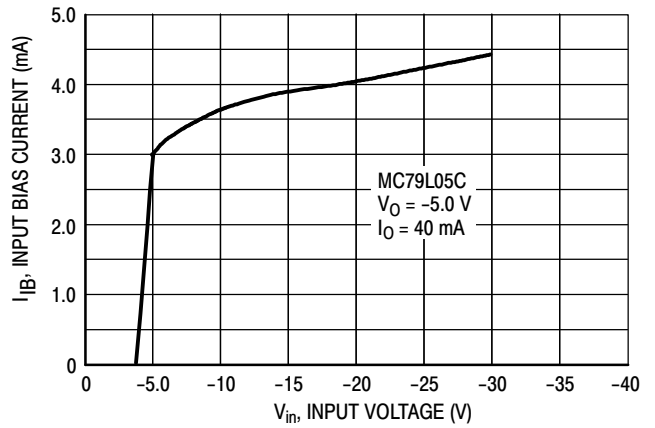


Figure 7. Input Bias Current versus Input Voltage

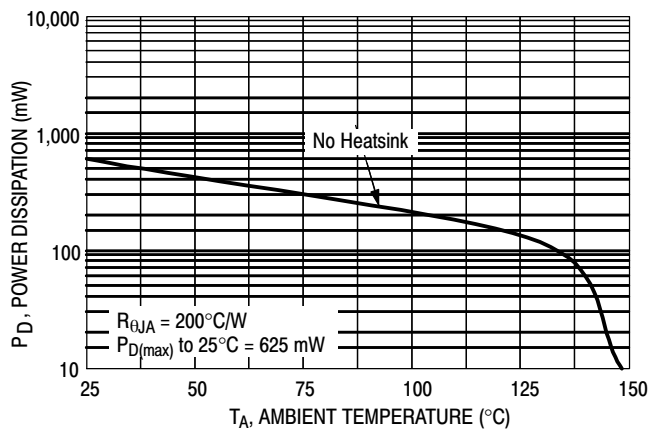


Figure 8. Maximum Average Power Dissipation versus Ambient Temperature (TO-92)

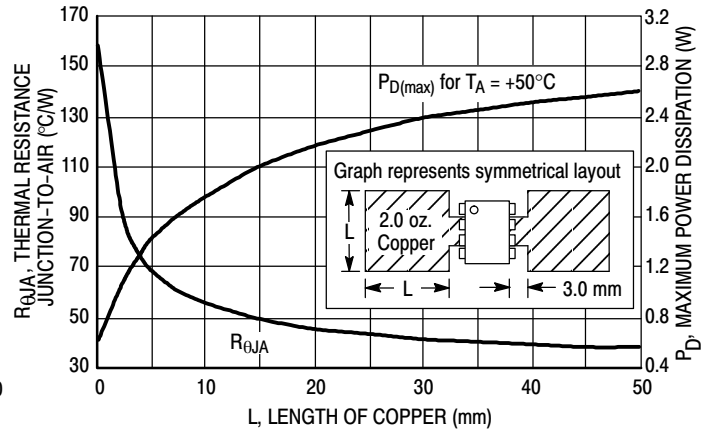


Figure 9. SOP-8 Thermal Resistance and Maximum Power Dissipation versus P.C.B. Copper Length

## MC79L00A Series

### ORDERING INFORMATION

Device	Nominal Voltage	Operating Temperature Range	Package	Shipping†
MC79L05ABDG	-5.0 V	TJ = -40° to +125°C	SOIC-8 (Pb-Free)	98 Units / Rail
MC79L05ABDR2G			SOIC-8 (Pb-Free)	2500 / Tape & Reel
MC79L05ABPG			TO-92 (Pb-Free)	2000 Units / Bag
MC79L05ABPRAG			TO-92 (Pb-Free)	2000 / Tape & Reel
MC79L05ACDG		TJ = 0° to +125°C	SOIC-8 (Pb-Free)	98 Units / Rail
MC79L05ACDR2G			SOIC-8 (Pb-Free)	2500 / Tape & Reel
MC79L05ACPG			TO-92 (Pb-Free)	2000 Units / Bag
MC79L05ACPRAG			TO-92 (Pb-Free)	2000 / Tape & Reel
MC79L05ACPRMG			TO-92 (Pb-Free)	2000 / Tape & Ammo Box
MC79L05ACPRPG			TO-92 (Pb-Free)	2000 / Tape & Ammo Box
MC79L12ABDG	-12 V	TJ = -40° to +125°C	SOIC-8 (Pb-Free)	98 Units / Rail
MC79L12ABDR2G			SOIC-8 (Pb-Free)	2500 / Tape & Reel
MC79L12ABPG			TO-92 (Pb-Free)	2000 Units / Bag
MC79L12ABPRAG			TO-92 (Pb-Free)	2000 / Tape & Reel
MC79L12ACDG	-12 V	TJ = 0° to +125°C	SOIC-8 (Pb-Free)	98 Units / Rail
MC79L12ACDR2G			SOIC-8 (Pb-Free)	2500 / Tape & Reel
MC79L12ACPG			TO-92 (Pb-Free)	2000 Units / Bag
MC79L12ACPRAG			TO-92 (Pb-Free)	2000 / Tape & Reel
MC79L12ACPRPG			TO-92 (Pb-Free)	2000 / Tape & Ammo Box

## MC79L00A Series

### ORDERING INFORMATION (continued)

Device	Nominal Voltage	Operating Temperature Range	Package	Shipping†
MC79L15ABDG	-15 V	TJ = -40° to +125°C	SOIC-8 (Pb-Free)	98 Units / Rail
MC79L15ABDR2G			SOIC-8 (Pb-Free)	2500 / Tape & Reel
MC79L15ABPG			TO-92 (Pb-Free)	2000 Units / Bag
MC79L15ABPRPG			TO-92 (Pb-Free)	2000 / Tape & Ammo Box
MC79L15ACDG		TJ = 0° to +125°C	SOIC-8 (Pb-Free)	98 Units / Rail
MC79L15ACDR2G			SOIC-8 (Pb-Free)	2500 / Tape & Reel
MC79L15ACPG			TO-92 (Pb-Free)	2000 Units / Bag
MC79L15ACPRAG			TO-92 (Pb-Free)	2000 / Tape & Reel
MC79L15ACPREG			TO-92 (Pb-Free)	2000 / Tape & Reel
MC79L15ACPRPG			TO-92 (Pb-Free)	2000 / Tape & Ammo Box
MC79L18ABPRPG		TJ = -40° to +125°C	TO-92 (Pb-Free)	2000 / Tape & Ammo Box
MC79L18ACPG		TJ = 0° to +125°C	TO-92 (Pb-Free)	2000 Units / Bag
MC79L24ABPG	-24 V	TJ = -40° to +125°C	TO-92 (Pb-Free)	2000 Units / Bag
MC79L24ACPG		TJ = 0° to +125°C	TO-92 (Pb-Free)	2000 Units / Bag
MC79L24ACPRMG			TO-92 (Pb-Free)	2000 / Tape & Ammo Box
MC79L24ACPRPG			TO-92 (Pb-Free)	2000 / Tape & Ammo Box

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

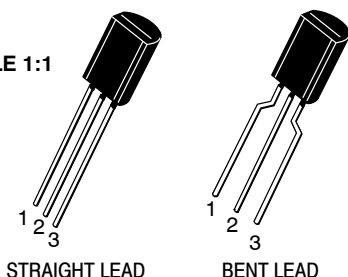


# MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

ON Semiconductor®

ON

SCALE 1:1

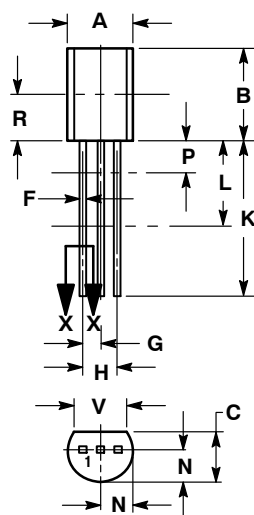


STRAIGHT LEAD

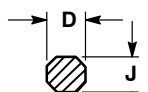
BENT LEAD

## TO-92 (TO-226) 1 WATT CASE 29-10 ISSUE A

DATE 08 MAY 2012



STRAIGHT LEAD

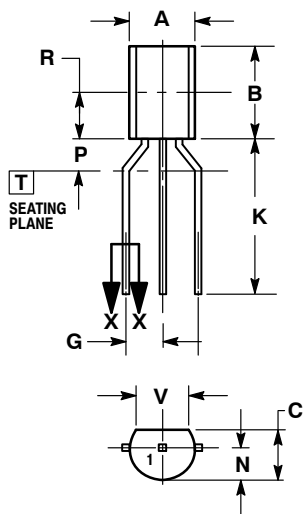


SECTION X-X

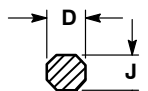
### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1994.
2. CONTROLLING DIMENSION: INCHES.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. DIMENSION F APPLIES BETWEEN DIMENSIONS P AND L. DIMENSIONS D AND J APPLY BETWEEN DIMENSIONS L AND K MINIMUM. THE LEAD DIMENSIONS ARE UNCONTROLLED IN DIMENSION P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.44	5.21
B	0.290	0.310	7.37	7.87
C	0.125	0.165	3.18	4.19
D	0.018	0.021	0.46	0.53
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.018	0.024	0.46	0.61
K	0.500	---	12.70	---
L	0.250	---	6.35	---
N	0.080	0.105	2.04	2.66
P	---	0.100	---	2.54
R	0.135	---	3.43	---
V	0.135	---	3.43	---



BENT LEAD



SECTION X-X


### NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: INCHES.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. DIMENSION F APPLIES BETWEEN DIMENSIONS P AND L. DIMENSIONS D AND J APPLY BETWEEN DIMENSIONS L AND K MINIMUM. THE LEAD DIMENSIONS ARE UNCONTROLLED IN DIMENSION P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.44	5.21
B	0.290	0.310	7.37	7.87
C	0.125	0.165	3.18	4.19
D	0.018	0.021	0.46	0.53
G	0.094	0.102	2.40	2.80
J	0.018	0.024	0.46	0.61
K	0.500	---	12.70	---
N	0.080	0.105	2.04	2.66
P	---	0.100	---	2.54
R	0.135	---	3.43	---
V	0.135	---	3.43	---

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**TO-92 (TO-226) 1 WATT**  
**CASE 29-10**  
**ISSUE A**

DATE 08 MAY 2012

STYLE 1: PIN 1. EMITTER 2. BASE 3. COLLECTOR	STYLE 2: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 3: PIN 1. ANODE 2. ANODE 3. CATHODE	STYLE 4: PIN 1. CATHODE 2. CATHODE 3. ANODE	STYLE 5: PIN 1. DRAIN 2. SOURCE 3. GATE
STYLE 6: PIN 1. GATE 2. SOURCE & SUBSTRATE 3. DRAIN	STYLE 7: PIN 1. SOURCE 2. DRAIN 3. GATE	STYLE 8: PIN 1. DRAIN 2. GATE 3. SOURCE & SUBSTRATE	STYLE 9: PIN 1. BASE 1 2. EMITTER 3. BASE 2	STYLE 10: PIN 1. CATHODE 2. GATE 3. ANODE
STYLE 11: PIN 1. ANODE 2. CATHODE & ANODE 3. CATHODE	STYLE 12: PIN 1. MAIN TERMINAL 1 2. GATE 3. MAIN TERMINAL 2	STYLE 13: PIN 1. ANODE 1 2. GATE 3. CATHODE 2	STYLE 14: PIN 1. EMITTER 2. COLLECTOR 3. BASE	STYLE 15: PIN 1. ANODE 1 2. CATHODE 3. ANODE 2
STYLE 16: PIN 1. ANODE 2. GATE 3. CATHODE	STYLE 17: PIN 1. COLLECTOR 2. BASE 3. EMITTER	STYLE 18: PIN 1. ANODE 2. CATHODE 3. NOT CONNECTED	STYLE 19: PIN 1. GATE 2. ANODE 3. CATHODE	STYLE 20: PIN 1. NOT CONNECTED 2. CATHODE 3. ANODE
STYLE 21: PIN 1. COLLECTOR 2. EMITTER 3. BASE	STYLE 22: PIN 1. SOURCE 2. GATE 3. DRAIN	STYLE 23: PIN 1. GATE 2. SOURCE 3. DRAIN	STYLE 24: PIN 1. EMITTER 2. COLLECTOR/ANODE 3. CATHODE	STYLE 25: PIN 1. MT 1 2. GATE 3. MT 2
STYLE 26: PIN 1. V <sub>CC</sub> 2. GROUND 2 3. OUTPUT	STYLE 27: PIN 1. MT 2. SUBSTRATE 3. MT	STYLE 28: PIN 1. CATHODE 2. ANODE 3. GATE	STYLE 29: PIN 1. NOT CONNECTED 2. ANODE 3. CATHODE	STYLE 30: PIN 1. DRAIN 2. GATE 3. SOURCE
STYLE 31: PIN 1. GATE 2. DRAIN 3. SOURCE	STYLE 32: PIN 1. BASE 2. COLLECTOR 3. EMITTER	STYLE 33: PIN 1. RETURN 2. INPUT 3. OUTPUT	STYLE 34: PIN 1. INPUT 2. GROUND 3. LOGIC	STYLE 35: PIN 1. GATE 2. COLLECTOR 3. EMITTER

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# MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

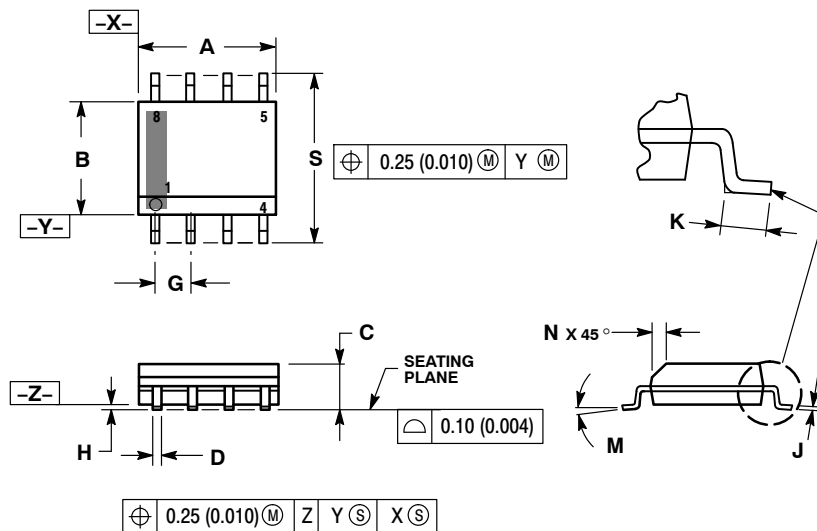
ON Semiconductor®



SCALE 1:1

SOIC-8 NB  
CASE 751-07  
ISSUE AK

DATE 16 FEB 2011

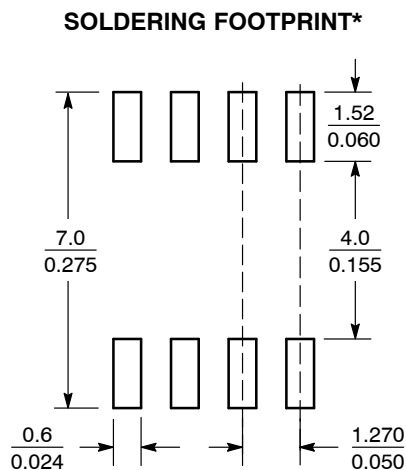


## NOTES:

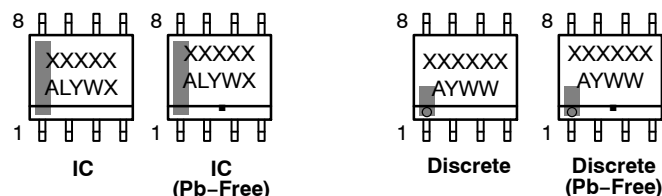
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.80	5.00	0.189	0.197
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27 BSC		0.050 BSC	
H	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
M	0°	8°	0°	8°
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

## GENERIC MARKING DIAGRAM\*



SCALE 6:1 (mm/inches)



XXXXXX = Specific Device Code  
A = Assembly Location  
L = Wafer Lot  
Y = Year  
W = Work Week  
■ = Pb-Free Package

XXXXXX = Specific Device Code  
A = Assembly Location  
Y = Year  
WW = Work Week  
■ = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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**SOIC-8 NB**  
**CASE 751-07**  
**ISSUE AK**

DATE 16 FEB 2011

<b>STYLE 1:</b> PIN 1. EMITTER 2. COLLECTOR 3. COLLECTOR 4. EMITTER 5. EMITTER 6. BASE 7. BASE 8. EMITTER	<b>STYLE 2:</b> PIN 1. COLLECTOR, DIE, #1 2. COLLECTOR, #1 3. COLLECTOR, #2 4. COLLECTOR, #2 5. BASE, #2 6. EMITTER, #2 7. BASE, #1 8. EMITTER, #1	<b>STYLE 3:</b> PIN 1. DRAIN, DIE #1 2. DRAIN, #1 3. DRAIN, #2 4. DRAIN, #2 5. GATE, #2 6. SOURCE, #2 7. GATE, #1 8. SOURCE, #1	<b>STYLE 4:</b> PIN 1. ANODE 2. ANODE 3. ANODE 4. ANODE 5. ANODE 6. ANODE 7. ANODE 8. COMMON CATHODE
<b>STYLE 5:</b> PIN 1. DRAIN 2. DRAIN 3. DRAIN 4. DRAIN 5. GATE 6. GATE 7. SOURCE 8. SOURCE	<b>STYLE 6:</b> PIN 1. SOURCE 2. DRAIN 3. DRAIN 4. SOURCE 5. SOURCE 6. GATE 7. GATE 8. SOURCE	<b>STYLE 7:</b> PIN 1. INPUT 2. EXTERNAL BYPASS 3. THIRD STAGE SOURCE 4. GROUND 5. DRAIN 6. GATE 3 7. SECOND STAGE Vd 8. FIRST STAGE Vd	<b>STYLE 8:</b> PIN 1. COLLECTOR, DIE #1 2. BASE, #1 3. BASE, #2 4. COLLECTOR, #2 5. COLLECTOR, #2 6. EMITTER, #2 7. EMITTER, #1 8. COLLECTOR, #1
<b>STYLE 9:</b> PIN 1. EMITTER, COMMON 2. COLLECTOR, DIE #1 3. COLLECTOR, DIE #2 4. EMITTER, COMMON 5. EMITTER, COMMON 6. BASE, DIE #2 7. BASE, DIE #1 8. EMITTER, COMMON	<b>STYLE 10:</b> PIN 1. GROUND 2. BIAS 1 3. OUTPUT 4. GROUND 5. GROUND 6. BIAS 2 7. INPUT 8. GROUND	<b>STYLE 11:</b> PIN 1. SOURCE 1 2. GATE 1 3. SOURCE 2 4. GATE 2 5. DRAIN 2 6. DRAIN 2 7. DRAIN 1 8. DRAIN 1	<b>STYLE 12:</b> PIN 1. SOURCE 2. SOURCE 3. SOURCE 4. GATE 5. DRAIN 6. DRAIN 7. DRAIN 8. DRAIN
<b>STYLE 13:</b> PIN 1. N.C. 2. SOURCE 3. SOURCE 4. GATE 5. DRAIN 6. DRAIN 7. DRAIN 8. DRAIN	<b>STYLE 14:</b> PIN 1. N-SOURCE 2. N-GATE 3. P-SOURCE 4. P-GATE 5. P-DRAIN 6. P-DRAIN 7. N-DRAIN 8. N-DRAIN	<b>STYLE 15:</b> PIN 1. ANODE 1 2. ANODE 1 3. ANODE 1 4. ANODE 1 5. CATHODE, COMMON 6. CATHODE, COMMON 7. CATHODE, COMMON 8. CATHODE, COMMON	<b>STYLE 16:</b> PIN 1. EMITTER, DIE #1 2. BASE, DIE #1 3. EMITTER, DIE #2 4. BASE, DIE #2 5. COLLECTOR, DIE #2 6. COLLECTOR, DIE #2 7. COLLECTOR, DIE #1 8. COLLECTOR, DIE #1
<b>STYLE 17:</b> PIN 1. VCC 2. V2OUT 3. V1OUT 4. TXE 5. RXE 6. VEE 7. GND 8. ACC	<b>STYLE 18:</b> PIN 1. ANODE 2. ANODE 3. SOURCE 4. GATE 5. DRAIN 6. DRAIN 7. CATHODE 8. CATHODE	<b>STYLE 19:</b> PIN 1. SOURCE 1 2. GATE 1 3. SOURCE 2 4. GATE 2 5. DRAIN 2 6. MIRROR 2 7. DRAIN 1 8. MIRROR 1	<b>STYLE 20:</b> PIN 1. SOURCE (N) 2. GATE (N) 3. SOURCE (P) 4. GATE (P) 5. DRAIN 6. DRAIN 7. DRAIN 8. DRAIN
<b>STYLE 21:</b> PIN 1. CATHODE 1 2. CATHODE 2 3. CATHODE 3 4. CATHODE 4 5. CATHODE 5 6. COMMON ANODE 7. COMMON ANODE 8. CATHODE 6	<b>STYLE 22:</b> PIN 1. I/O LINE 1 2. COMMON CATHODE/VCC 3. COMMON CATHODE/VCC 4. I/O LINE 3 5. COMMON ANODE/GND 6. I/O LINE 4 7. I/O LINE 5 8. COMMON ANODE/GND	<b>STYLE 23:</b> PIN 1. LINE 1 IN 2. COMMON ANODE/GND 3. COMMON ANODE/GND 4. LINE 2 IN 5. LINE 2 OUT 6. COMMON ANODE/GND 7. COMMON ANODE/GND 8. LINE 1 OUT	<b>STYLE 24:</b> PIN 1. BASE 2. EMITTER 3. COLLECTOR/ANODE 4. COLLECTOR/ANODE 5. CATHODE 6. CATHODE 7. COLLECTOR/ANODE 8. COLLECTOR/ANODE
<b>STYLE 25:</b> PIN 1. VIN 2. N/C 3. REXT 4. GND 5. IOUT 6. IOUT 7. IOUT 8. IOUT	<b>STYLE 26:</b> PIN 1. GND 2. dv/dt 3. ENABLE 4. ILIMIT 5. SOURCE 6. SOURCE 7. SOURCE 8. VCC	<b>STYLE 27:</b> PIN 1. ILIMIT 2. OVLO 3. UVLO 4. INPUT+ 5. SOURCE 6. SOURCE 7. SOURCE 8. DRAIN	<b>STYLE 28:</b> PIN 1. SW_TO_GND 2. DASIC_OFF 3. DASIC_SW_DET 4. GND 5. V_MON 6. VBULK 7. VBULK 8. VIN
<b>STYLE 29:</b> PIN 1. BASE, DIE #1 2. EMITTER, #1 3. BASE, #2 4. EMITTER, #2 5. COLLECTOR, #2 6. COLLECTOR, #2 7. COLLECTOR, #1 8. COLLECTOR, #1	<b>STYLE 30:</b> PIN 1. DRAIN 1 2. DRAIN 1 3. GATE 2 4. SOURCE 2 5. SOURCE 1/DRAIN 2 6. SOURCE 1/DRAIN 2 7. SOURCE 1/DRAIN 2 8. GATE 1		

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